

- AVAILABLE IN JAN, JANTX, JANTXV, AND JANS PER MIL-PRF-19500/533
- 500 mW ZENER DIODES
- NON CAVITY CONSTRUCTION
- METALLURGICALLY BONDED

1N6309
THRU
1N6320

MAXIMUM RATINGS

Operating Temperature: -65°C to +175°C
 Storage Temperature: -65°C to +175°C
 Power Dissipation: 500 mW @ $T_L=+75^\circ\text{C}$ @ $L=3/8"$
 Power Derating: 5mW/°C above $T_L=+75^\circ\text{C}$
 Forward Voltage: 1.4V dc @ $I_F=1\text{A}$ dc (Pulsed)

ELECTRICAL CHARACTERISTICS @ 25°C, unless otherwise specified

TYPE	V_{Z2} NOM. ±5% @ I_{Z2}	V_{Z1} MIN. @ I_{Z1} 250μA	I_{Z2} TEST CURRENT	Z_Z @ I_{Z2}	Z_{ZK} @ 250μA	I_{ZM}	V_Z (reg) ΔV_Z (1)	I_{ZSM} SURGE	V_R	I_{R1} @ 25°C	I_{R2} @ TA= 150°C	N_D @250 μA 1-3 kHz
	VOLTS	VOLTS	mA	OHMS	OHMS	mA	VOLTS	AMPS	VOLTS	μA	μA	μ
1N6309	2.4	1.1	20	30	1200	177	1.5	2.5	1.0	100	200	1.0
1N6310	2.7	1.2	20	30	1300	157	1.5	2.2	1.0	60	150	1.0
1N6311	3.0	1.3	20	29	1400	141	1.5	2.0	1.0	30	100	1.0
1N6312	3.3	1.5	20	24	1400	128	1.6	1.8	1.0	5.0	20	1.0
1N6313	3.6	1.8	20	22	1400	117	1.6	1.65	1.0	3.0	12	1.0
1N6314	3.9	2.0	20	20	1700	108	1.6	1.5	1.0	2.0	12	1.0
1N6315	4.3	2.4	20	18	1400	99	0.9	1.4	1.0	2.0	12	1.0
1N6316	4.7	2.8	20	16	1500	90	0.5	1.27	1.5	5.0	12	1.0
1N6317	5.1	3.3	20	14	1300	83	0.4	1.17	2.0	5.0	12	1.0
1N6318	5.6	4.3	20	8.0	1200	76	0.4	1.10	2.5	5.0	10	2.0
1N6319	6.2	5.2	20	3.0	800	68	0.3	0.97	3.5	5.0	10	5.0
1N6320	6.8	6.0	20	3.0	400	63	0.35	1.23	4.0	2.0	50	5.0

NOTE 1 $\Delta V_Z = V_Z @ 20 \text{ mAdc}$ minus $V_Z @ 2 \text{ mAdc}$

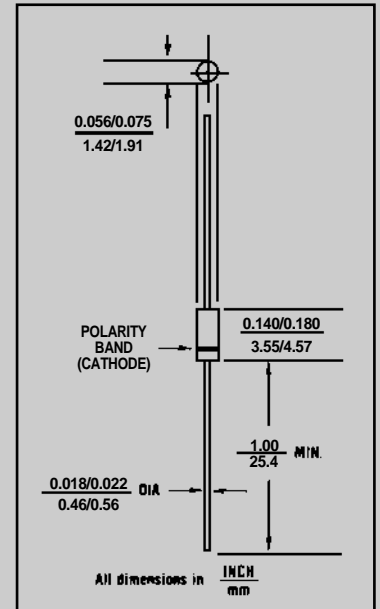


FIGURE 1

DESIGN DATA

CASE: Hermetically sealed, Glass "D"
 Body per MIL-PRF- 19500/533. D-5D

LEAD MATERIAL: Copper clad steel

LEAD FINISH: Tin / Lead

THERMAL RESISTANCE: ($R_{\theta JL}$): 250
 °C/W maximum

THERMAL IMPEDANCE: ($Z_{\theta JX}$): 15
 °C/W maximum

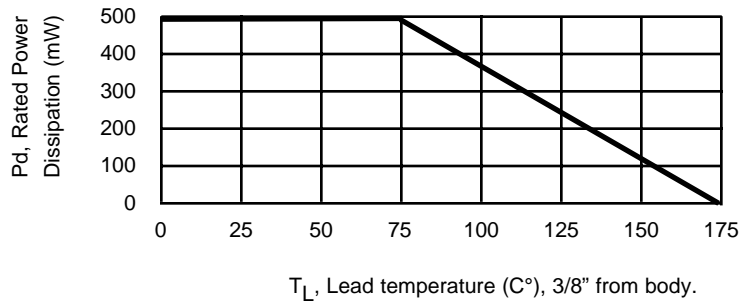
POLARITY: Diode to be operated with
 the banded (cathode) end positive.

MOUNTING POSITION: Any



1N6309 thru 1N6320

FIGURE 2



POWER DERATING CURVE

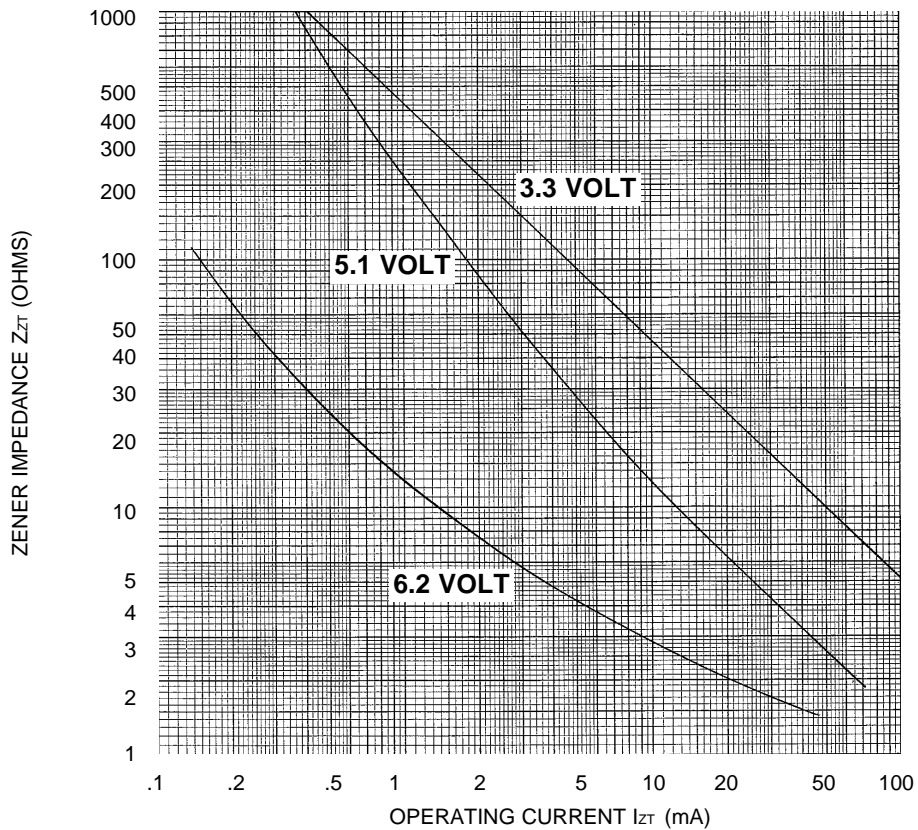


FIGURE 3

ZENER IMPEDANCE VS. OPERATING CURRENT